## NSN 5961-01-335-5527

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-335-5527 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Terminal Length:** 0.312 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage/static/base open **Power Rating Per Characteristic:** 116.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter and 90.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No